BLF0910H9LS600

Power LDMOS transistor Rev. 1 — 8 January 2018

AMMPLEON

Product data sheet

Product profile 1.

1.1 General description

A 600 W LDMOS power transistor for industrial applications at frequency of 915 MHz.

The BLF0910H9LS600 is designed for high-power CW applications and is assembled in a high performance ceramic package.

Typical performance

RF performance at V_{DS} = 50 V; I_{Dq} = 90 mA in a class-AB application circuit.

Test signal	f	V _{DS}	P_L	G _p	ησ
	(MHz)	(V)	(W)	(dB)	(%)
CW	915	50	600	19.8	68.5

1.2 Features and benefits

- High efficiency
- Easy power control
- Excellent ruggedness
- Integrated ESD protection
- Designed for broadband operation (900 MHz to 930 MHz)
- Internally input matched
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

1.3 Applications

Industrial applications in the 915 MHz ISM band

2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
1	drain		,
2	gate		1
3	source [1]	2	2 3
			sym112

^[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

Type number	Packag	Package		
	Name	Description	Version	
BLF0910H9LS600	-	earless flanged ceramic package; 2 leads	SOT502B	

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Min	Max	Unit
V_{DS}	drain-source voltage	-	108	V
V_{GS}	gate-source voltage	-6	+11	V
T _{stg}	storage temperature	-65	+150	°C
Tj	junction temperature [1]	-	225	°C

^[1] Continuous use at maximum temperature will affect the reliability, for details refer to the online MTF calculator.

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
$R_{\text{th(j-case)}}$	thermal resistance from junction to case	$T_{case} = 90 ^{\circ}C; P_{L} = 600 W$	0.174	K/W

6. Characteristics

Table 6. DC characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 4 \text{ mA}$	108	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	V _{DS} = 10 V; I _D = 400 mA	1.5	1.9	2.5	V
I _{DSS}	drain leakage current	V _{GS} = 0 V; V _{DS} = 50 V	-	-	2.8	μА
I _{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$	-	70	-	Α
I _{GSS}	gate leakage current	V _{GS} = 11 V; V _{DS} = 0 V	-	-	280	nA
g _{fs}	forward transconductance	V _{DS} = 10 V; I _D = 20 A	-	30.5	-	S
R _{DS(on)}	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $I_D = 14 \text{ A}$	-	0.0575	-	Ω

Table 7. RF characteristics

Test signal: CW; f = 915 MHz; RF performance at V_{DS} = 50 V; I_{Dq} = 90 mA; T_{case} = 25 °C; unless otherwise specified; in a class-AB production test circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
G _p	power gain	P _L = 600 W	17.7	18.6	-	dB
RLin	input return loss	P _L = 600 W	-	-17.7	-9.0	dB
η_{D}	drain efficiency	P _L = 600 W	62.0	65.7	-	%

7. Test information

7.1 Ruggedness in class-AB operation

The BLF0910H9LS600 is capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions: V_{DS} = 50 V; I_{Dq} = 90 mA; P_{L} = 600 W (CW); tested in band with soft power ramp up across predefined integer phase steps.

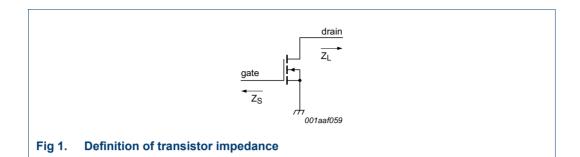
7.2 Impedance information

Table 8. Typical impedance

Measured load-pull Z_S and Z_L device impedances; $I_{Dq} = 90$ mA; $V_{DS} = 50$ V; typical values unless otherwise specified.

f	Z _S [1]	Z _L [1]
(MHz)	(Ω)	(Ω)
915	1.5 – 1.6j	0.45 + 0.2j

[1] Z_S and Z_L defined in Figure 1.



7.3 Test circuit

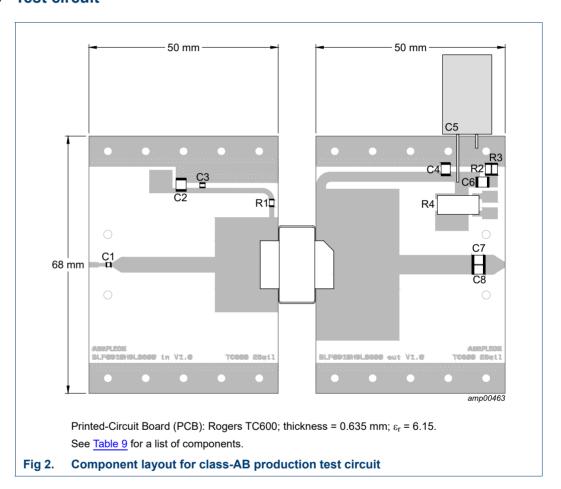


Table 9. List of components

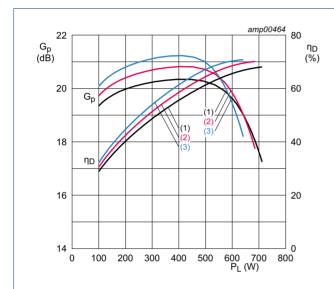
For test circuit see Figure 2.

Component	Description	Value	Remarks
C1, C3	multilayer ceramic chip capacitor	100 pF	ATC100A101JW150XT
C2, C6	multilayer ceramic chip capacitor	4.7 μF, 100 V	C3225X7S2A475K200AE
C4, C7, C8	multilayer ceramic chip capacitor	51 pF	ATC100B510FW500XT
C5	electrolytic capacitor	470 μF, 63 V	MAL203858471E3

Table 9. List of components ...continued For test circuit see Figure 2.

Component	Description	Value	Remarks
R1	chip resistor	10 Ω	MCMR06X10R0FTL
R2, R3	chip resistor	6.2 Ω	MC0125W120616R20
R4	shunt resistor	0.01 Ω	Ohmite: FC4L110R010FER

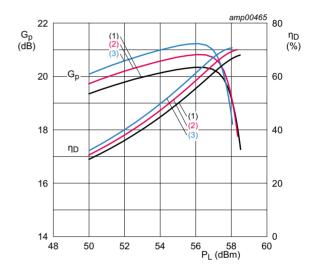
7.4 Graphical data



 $V_{DS} = 50 \text{ V}; I_{Dq} = 90 \text{ mA}.$

- (1) f = 902 MHz
- (2) f = 915 MHz
- (3) f = 928 MHz

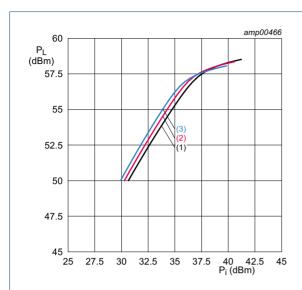
Fig 3. Power gain and drain efficiency as function of output power; typical values



 $V_{DS} = 50 \text{ V}; I_{Dq} = 90 \text{ mA}.$

- (1) f = 902 MHz
- (2) f = 915 MHz
- (3) f = 928 MHz

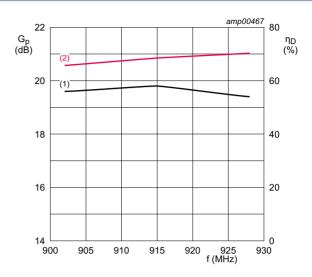
Fig 4. Power gain and drain efficiency as function of output power; typical values



 $V_{DS} = 50 \text{ V}; I_{Dq} = 90 \text{ mA}.$

- (1) f = 902 MHz
- (2) f = 915 MHz
- (3) f = 928 MHz

Fig 5. Output power as a function of input power; typical values



 V_{DS} = 50 V; I_{Dq} = 90 mA; P_{L} = 600 W.

- (1) G_p
- (2) η_D

Fig 6. Power gain and drain efficiency as a function of frequency; typical values

8. Package outline

Earless flanged ceramic package; 2 leads

SOT502B

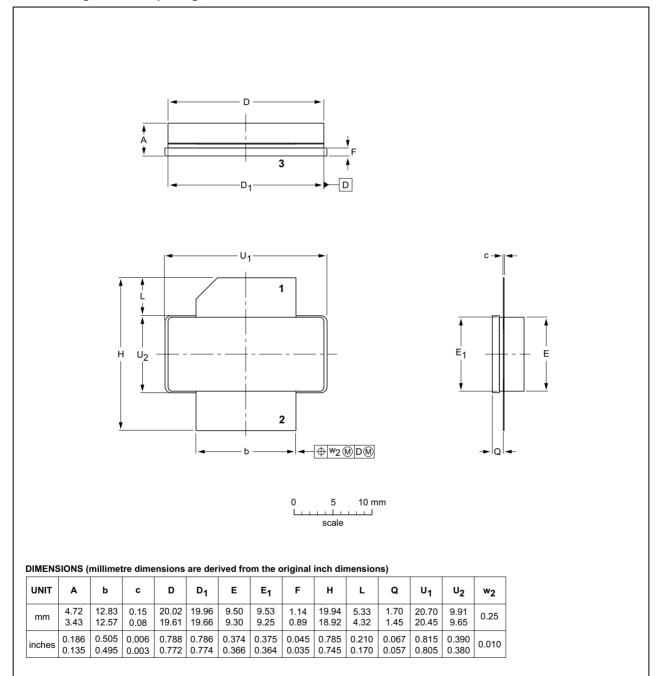


Fig 7. Package outline SOT502B

IEC

OUTLINE

VERSION

SOT502B

JEITA

REFERENCES

JEDEC

ISSUE DATE

07-05-09

12-05-02

EUROPEAN

PROJECTION

9. Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

Table 10. ESD sensitivity

ESD model	Class
Charged Device Model (CDM); According to ANSI/ESDA/JEDEC standard JS-002	C2A [1]
Human Body Model (HBM); According to ANSI/ESDA/JEDEC standard JS-001	2 [2]

- [1] CDM classification C2A is granted to any part that passes after exposure to an ESD pulse of 500 V, but fails after exposure to an ESD pulse of 750 V.
- [2] HBM classification 2 is granted to any part that passes after exposure to an ESD pulse of 2000 V, but fails after exposure to an ESD pulse of 4000 V.

10. Abbreviations

Table 11. Abbreviations

Acronym	Description
CW	Continuous Wave
ESD	ElectroStatic Discharge
ISM	Industrial, Scientific and Medical
LDMOS	Laterally Diffused Metal-Oxide Semiconductor
MTF	Median Time to Failure
VSWR	Voltage Standing-Wave Ratio

11. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BLF0910H9LS600 v.1	20180108	Product data sheet	-	-

12. Legal information

12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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